

گروه فنی مهندسی جوش و برش مقدم

اعتماد از شما کیفیت و تخصص از ما



09153223758



051-37581400



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مشهد خیام شمالی 63 خیابان پردیس 3

برای کسب اطلاعات بیشتر بر روی لینک ها کلیک کنید

- 7 سال سابقه آموزش تعمیرات تخصصی دستگاه های جوش اینورتری تک فاز و 3 فاز
- 7 سال سابقه فروش قطعات الکترونیکی دستگاه جوش
 تک فاز و 3 فاز
- آموزش تخصصی تحلیل دستگاه های جوش اینورتری مختص ابراز فروشان
 - آموزش تخصصی ابراز آلات شارژی

Amplifier Transistors

PNP Silicon

Features

Pb–Free Packages are Available*

http://onsemi.com

COLLECTOR 1

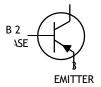
MAXIMUM RATINGS

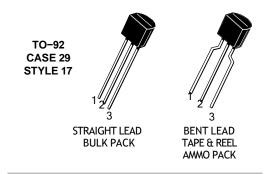
Rating	Symbol	Value	Unit
Collector - Emitter Voltage BC556 BC557 BC558	V _{CEO}	-65 -45 -30	Vdc
Collector - Base Voltage BC556 BC557 BC558	V _{CBO}	-80 -50 -30	Vdc
Emitter - Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current - Continuous - Peak	Ic I _{CM}	-100 -200	mAdc
Base Current - Peak	I _{BM}	-200	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

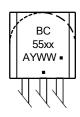
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.





MARKING DIAGRAM



xx = 6B, 7A, 7B, 7C, or 8B A = Assembly Location

Y = Year WW = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Publication Order Number:

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			•	•	•	•
Collector – Emitter Breakdown Voltage (I _C = -2.0 mAdc, I _B = 0)	BC556 BC557 BC558	V _{(BR)CEO}	-65 -45 -30	- - -	- - -	V
Collector – Base Breakdown Voltage (I _C = –100 μAdc)	BC556 BC557 BC558	V _{(BR)CBO}	-80 -50 -30	- - -	- - -	V
Emitter – Base Breakdown Voltage (I _E = –100 μAdc, I _C = 0)	BC556 BC557 BC558	$V_{(BR)EBO}$	-5.0 -5.0 -5.0	- - -	- - -	V
Collector-Emitter Leakage Current (V _{CES} = -40 V) (V _{CES} = -20 V) (V _{CES} = -20 V, T _A = 125°C)	BC556 BC557 BC558 BC556 BC557 BC558	I _{CES}	- - - -	-2.0 -2.0 -2.0 -	-100 -100 -100 -4.0 -4.0 -4.0	nA μA
ON CHARACTERISTICS	2000				4.0	
DC Current Gain ($I_C = -10 \mu Adc$, $V_{CE} = -5.0 V$) ($I_C = -2.0 \text{ mAdc}$, $V_{CE} = -5.0 V$)	A Series Device B Series Devices C Series Devices BC557 A Series Device B Series Devices C Series Devices	h _{FE}	- - - 120 120 180 420	90 150 270 - 170 290 500	- - - 800 220 460 800	-
$(I_C = -100 \text{ mAdc}, V_{CE} = -5.0 \text{ V})$	A Series Device B Series Devices C Series Devices		- - -	120 180 300	- - -	
Collector – Emitter Saturation Voltage (I _C = -10 mAdc, I _B = -0.5 mAdc) (I _C = -10 mAdc, I _B = see Note 1) (I _C = -100 mAdc, I _B = -5.0 mAdc)		V _{CE(sat)}		-0.075 -0.3 -0.25	-0.3 -0.6 -0.65	V
Base – Emitter Saturation Voltage (I_C = -10 mAdc, I_B = -0.5 mAdc) (I_C = -100 mAdc, I_B = -5.0 mAdc)		V _{BE(sat)}	- -	-0.7 -1.0	- -	V
Base-Emitter On Voltage (IC = -2.0 mAdc, V _{CE} = -5.0 Vdc) (I _C = -10 mAdc, V _{CE} = -5.0 Vdc)		V _{BE(on)}	-0.55 -	-0.62 -0.7	-0.7 -0.82	V
SMALL-SIGNAL CHARACTERISTICS			_	•		
Current – Gain – Bandwidth Product ($I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V}, f = 100 \text{ MHz}$)	BC556 BC557 BC558	fτ	- - -	280 320 360	- - -	MHz
Output Capacitance ($V_{CB} = -10 \text{ V}$, $I_{C} = 0$, $f = 1.0 \text{ MHz}$)		C_{ob}	_	3.0	6.0	pF
Noise Figure (I _C = -0.2 mAdc, V _{CE} = -5.0 V, R _S = 2.0 k Ω , f = 1.0 kHz, Δ f = 200 Hz)	BC556 BC557 BC558	NF	- - -	2.0 2.0 2.0	10 10 10	dB
Small-Signal Current Gain (I _C = −2.0 mAdc, V _{CE} = 5.0 V, f = 1.0 kHz)	BC557 A Series Device B Series Devices C Series Devices	h _{fe}	125 125 240 450	- - - -	900 260 500 900	-

^{1.} $I_C = -10$ mAdc on the constant base current characteristics, which yields the point $I_C = -11$ mAdc, $V_{CE} = -1.0$ V.

BC557/BC558

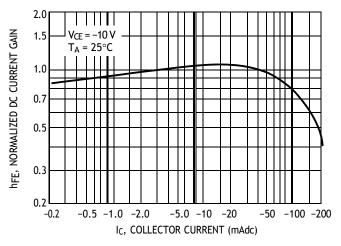


Figure 1. Normalized DC Current Gain

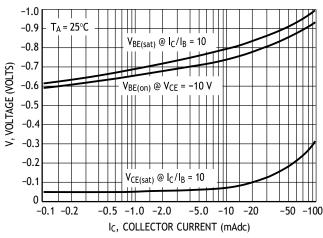


Figure 2. "Saturation" and "On" Voltages

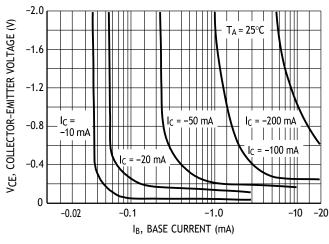


Figure 3. Collector Saturation Region

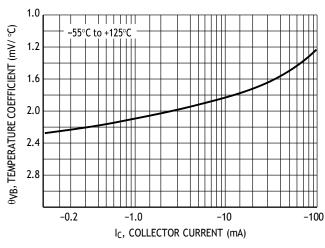


Figure 4. Base-Emitter Temperature Coefficient

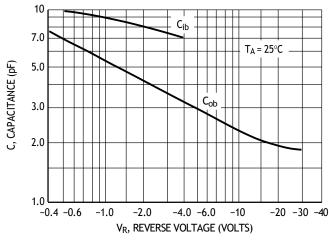


Figure 5. Capacitances

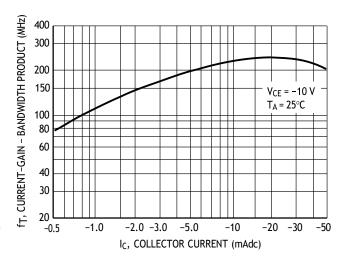


Figure 6. Current-Gain - Bandwidth Product

BC556

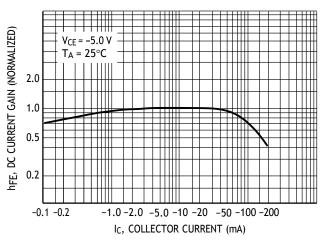


Figure 7. DC Current Gain

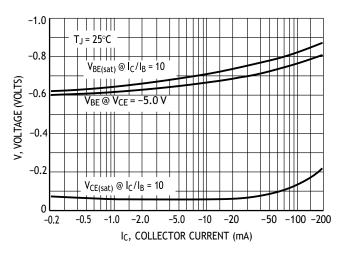


Figure 8. "On" Voltage

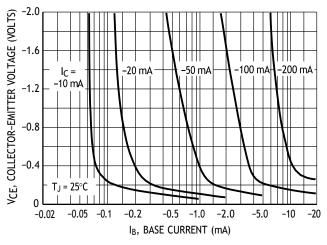


Figure 9. Collector Saturation Region

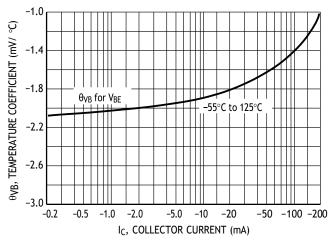


Figure 10. Base-Emitter Temperature Coefficient

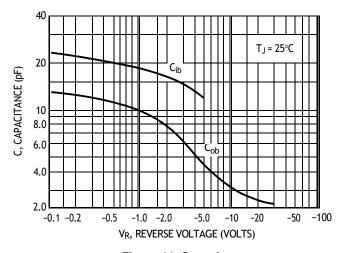


Figure 11. Capacitance

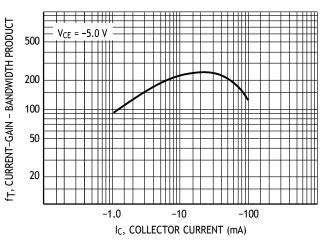


Figure 12. Current-Gain - Bandwidth Product

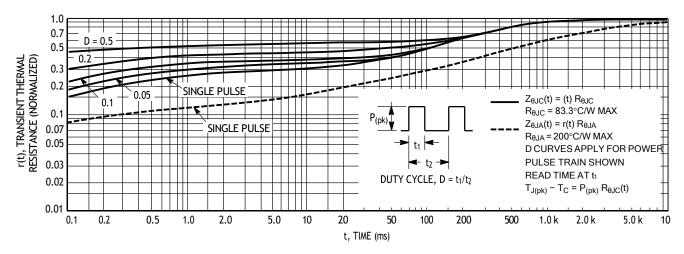


Figure 13. Thermal Response

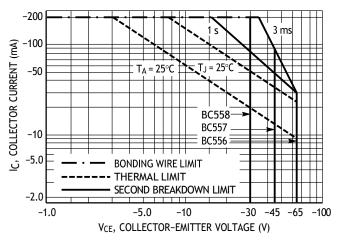


Figure 14. Active Region - Safe Operating Area

The safe operating area curves indicate I_{C} – V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

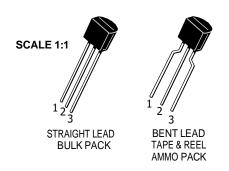
The data of Figure 14 is based upon $T_{J(pk)}$ = 150°C; T_C or T_A is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq$ 150°C. $T_{J(pk)}$ may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

ORDERING INFORMATION

Device	Package	Shipping [†]
BC556BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC556BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC557AZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC557BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC557BRL1	TO-92	2000 / Tape & Reel
BC557BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC557BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC557CG	TO-92 (Pb-Free)	5000 Units / Bulk
BC557CZL1G	TO-92 (Pb-Free)	2000 / Ammo Box
BC558BRLG	TO-92 (Pb-Free)	2000 / Tape & Reel
BC558BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
BC558BZL1G	TO-92 (Pb-Free)	2000 / Ammo Box

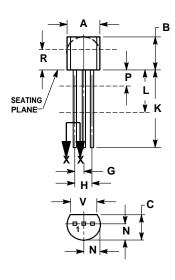
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





TO-92 (TO-226) CASE 29-11 **ISSUE AM**

DATE 09 MAR 2007



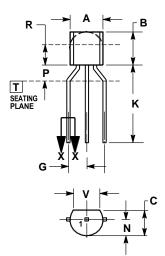
STRAIGHT LEAD **BULK PACK**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI DIMENSIONING AND TOLERANGING FER AND TY14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R
 IS UNCONTROLLED.

- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	METERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
٧	0.135		3.43		



BENT LEAD TAPE & REEL AMMO PACK



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.

- CONTROLLING DIMENSION: MILLIMETERS.
 CONTOUR OF PACKAGE BEYOND
 DIMENSION R IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P
 AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS				
DIM	MIN	MAX			
Α	4.45	5.20			
В	4.32	5.33			
С	3.18	4.19			
D	0.40	0.54			
G	2.40	2.80			
J	0.39	0.50			
K	12.70				
N	2.04	2.66			
Р	1.50	4.00			
R	2.93				
V	3 //3				

STYLES ON PAGE 2

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TO-92 (TO-226) CASE 29-11 ISSUE AM

DATE 09 MAR 2007

STYLE 1: PIN 1. 2. 3.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE EMITTER COLLECTOR	PIN 1. 2.	ANODE ANODE CATHODE	2.	CATHODE	2.	DRAIN
	GATE	STYLE 7: PIN 1. 2. 3.	DRAIN	PIN 1. 2.	DRAIN GATE SOURCE & SUBSTRATE	PIN 1. 2.	BASE 1 EMITTER	2.	CATHODE GATE ANODE
2.	CATHODE & ANODE	2	MAIN TERMINAL 1 GATE MAIN TERMINAL 2	2	GATE	PIN 1.	EMITTER COLLECTOR BASE	PIN 1. 2.	
PIN 1. 2.	ANODE GATE	PIN 1. 2.	BASE	PIN 1. 2.		PIN 1. 2.	GATE ANODE	2.	NOT CONNECTED
PIN 1. 2.		PIN 1.	SOURCE GATE	PIN 1.	GATE	PIN 1. 2.	EMITTER COLLECTOR/ANODE CATHODE	PIN 1. 2.	MT 1
	V _{CC}	PIN 1.	MT SUBSTRATE	PIN 1.	CATHODE ANODE	PIN 1. 2.	NOT CONNECTED ANODE CATHODE	PIN 1. 2.	DRAIN
		PIN 1. 2.	BASE COLLECTOR EMITTER	PIN 1. 2.	RETURN	PIN 1. 2.			

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